SiC Power Module

BSM300D12P4G101

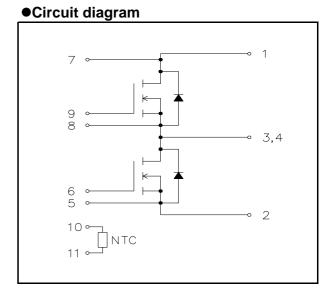
Datasheet

Application

- · Motor drive
- · Inverter, Converter
- · Photovoltaics, wind power generation.
- · Induction heating equipment.

Features

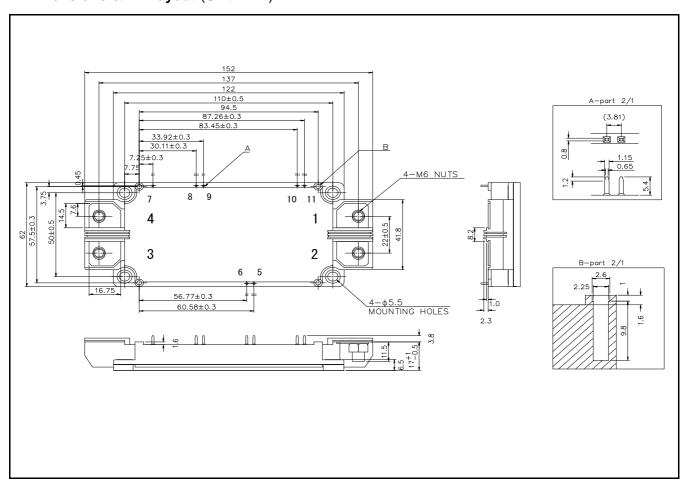
- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.



●Construction

This product is a half bridge module consisting of SiC-UMOSFET from ROHM.

● Dimensions & Pin layout (Unit : mm)



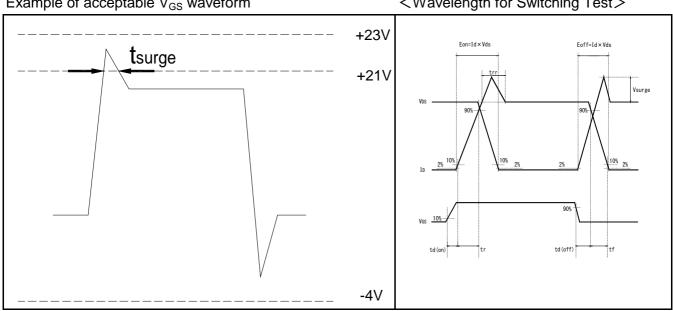
◆Absolute maximum ratings (T_i = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit	
Drain - Source Voltage	V_{DSS}	G-S short	1200	- V	
Gate - Source Voltage (+)	V_{GSS}	D-S short	21		
Gate - Source Voltage (-)	V_{GSS}	D-S short	-4		
G - S Voltage (t _{surge} <300nsec)	V _{GSSsurge}	D-S short Note 1)	-4 to 23		
Drain Current Note 2)	I _D	DC(Tc=60°C) V _{GS} =18V	291		
	I _{DRM}	Pulse (Tc = 60° C) 1ms V _{GS} = $18V$ _{Note 3)}	600		
Source Current Note 2)	I _S	DC(Tc=60°C) V _{GS} =18V	291	Α	
	I _{SRM}	Pulse (Tc = 60° C) 1ms V _{GS} = $18V$ _{Note 3)}	600		
	I _{SRM}	Pulse (Tc = 60°C) 1.5µs V _{GS} =0V _{Note 3) 4)}	600		
Total Power Dissipation Note 5)	Ptot	Tc = 25°C	925	W	
Max Junction Temperature	Tjmax		175		
Junction Temperature	Tjop		-40 to 150	°C	
Storage Temperature	ge Temperature Tstg		-40 to 125		
Isolation Voltage	Visol	Terminals to baseplate f = 60Hz AC 1 min.	2500	Vrms	
Mounting Torque		Main Terminals : M6 screw	4.5	N·m	
Mounting Torque	-	Mounting to heat sink M5 screw	3.5		

- Please note especially when using driver source that V_{GSSsurge} must be in the range of Note 1) absolute maximum rating.
- Note 2) Case temperature (Tc) is defined on the surface of base plate just under the chips.
- Note 3) Repetition rate should be kept within the range where temperature rise if die should not exceed Tjmax.
- Note 4) Repititive pulse, PW \leq 1.5 μ s, Duty cycle \leq 5%
- Tj is less than 175°C. Note 5)

Example of acceptable V_{GS} waveform

<Wavelength for Switching Test>



●Electrical characteristics (T_i=25°C)

Parameter	Parameter Symbol Conditions		Ratings			Unit	
			Min.	Тур.	Max.	Offic	
On-state static Drain-Source Voltage	Vos(on)		Tj=25°C	_	1.2	1.6	V
		$I_{D} = 300A, V_{GS} = 18V$	Tj=125°C	_	1.9	_	
		Tj=15			2.2	2.9	
Drain Cutoff Current	IDSS	V _{DS} =1200V,V _{GS} =0V		_	_	1	mA
Souce-Drain Voltage	V_{SD}	Tj=25°C		_	3.9	_	
		Vgs=0V,Is=300A	Tj=125°C	_	4.1	_	V
			Tj=150°C	_	4.2	_	
		V _{GS} =18V,I _S =300A	Tj=25°C	_	1.2	_	
			Tj=125°C	_	1.8	_	
			Tj=150°C	_	2.1	_	
Gate-Source Threshold Voltage	Vgs(th)	V _{DS} =10V,I _D =145.6mA _{Note 6)}		2.8	-	4.8	V
Gate-Source	Igss	Vgs=21V,Vps=0V		_	_	0.5	
Leak Current		VGS=-4V,VDS=0V			_	_	μA
Switching Characteristics	td(on)	Vgs(on)=18V, Vgs(off)=0V			63	_	
	tr	V _{DS} =600V I _D =300A Rg(on)=3.9 ohm, Rg(off)=3.3 ohm Inductive load		_	45	_	ns
	trr			_	24	_	
	td (off)			_	270	_	
	tf			_	57	_	
Input Capacitance	Ciss	VDS=10V,VGS=0V,200kHz		_	30	_	nF
Gate Registance	RGint	Tj=25°C		_	0.25	_	Ω
NTC Rated Resistance	R25			_	5.0	_	kΩ
NTC B Value	B _{25/50}			_	3370	_	K
Stray Inductance	Ls			_	14.5	_	nΗ
Creepage Distance	-	Terminal to heat sink		_	16.7	_	mm
		Terminal to terminal		_	16.7	_	mm
Clearance Distance	-	Terminal to heat sink		_	12.0	_	mm
		Terminal to terminal		_	11.0	_	mm
Junction-to -Case Thermal Resistance	Rth(j-c)	UMOSFET(1/2 module) Note 7)			_	162	°C/kW
Case-to -heat sink Thermal Resistance	Rth(c-f)	Case to heat sink, per 1 module. Thermal grease applied. Note 8)			15	_	

- Note 6) Tested after applying $V_{GS} = 21V$ for 100ms.
- Note 7) Measurement of Tc is to be done at the point just under the chip.
- Note 8) Typical value is measured by using thermally conductive grease of $\lambda=0.9W/(m\cdot K)$.
- Note 9) SiC devices have lower short cuicuit withstand capability due to high current density. Please be advised to pay careful attention to short cuicuit accident and try to adjust protection time to shutdown them as short as possible.
- Note 10) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be dameged, please replace such Product with a new one.

Fig.1 Output characteristic 25°C (TYP) 600 $V_{GS}=14V$ 500 V_{GS}=16V Drain Current I_D (A) 400 V_{GS}=12V $V_{GS}=18V$ 300 V_{GS}=20V 200 V_{GS}=10V 100 0 1.5 0 0.5 2.5 Drain source voltage V_{DS} (V)

(TYP) 3.5 Tj=150°C Drain source voltage V_{DS} (V) V_{GS}=18V 3 2.5 Tj=125°C 2 1.5 Tj=25°C 0.5 0 100 200 300 400 500 600 0 Drain current I_D (A)

Fig.2 Drain source voltage characteristic

Fig.3 Drain source voltage characteristic 25°C (TYP)

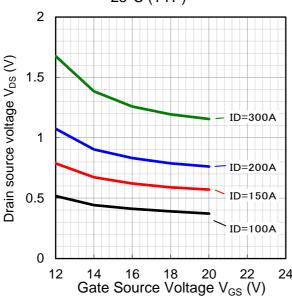


Fig.4 Ron vs Tj characteristic (TYP)

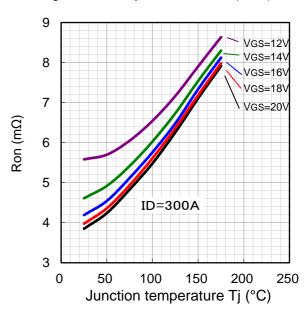


Fig.5 Forward characteristic of Diode (TYP)

1000

V_{GS}=18V

V_{GS}=0V

Tj=150°C

Tj=25°C

0.1

Source drain voltage V_{SD} (V)

Fig.6 Forward characteristic of Diode (TYP) 600 Tj=25°C 500 V_{GS}=18∖ Source current Is (A) 400 300 200 Tj=150°C 100 Tj=125°C 0 5

Fig.7 Drain Current vs Gate Voltage (TYP)

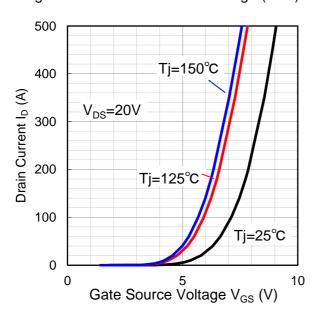


Fig.8 Drain Current vs Gate Voltage (TYP)

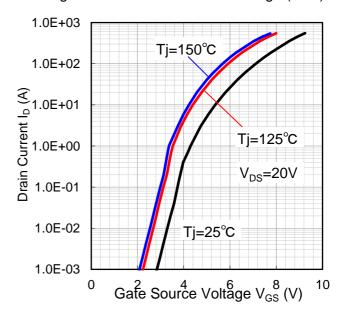


Fig.9 Switching time vs drain current at 25°C (TYP)

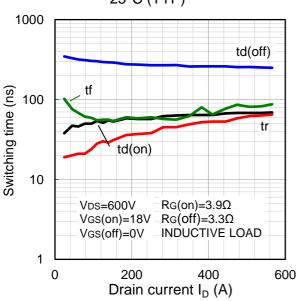


Fig.10 Switching time vs drain current at 125°C (TYP)

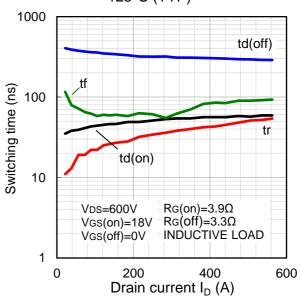


Fig.11 Switching time vs drain current at 150°C (TYP)

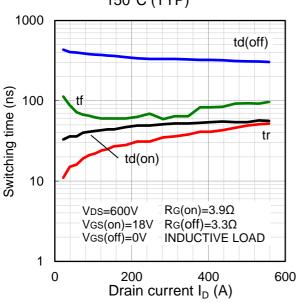


Fig.12 Switching loss vs drain current at 25°C (TYP)

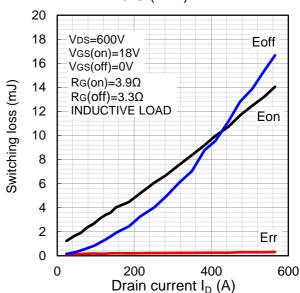


Fig.13 Switching loss vs drain current at 125°C (TYP)

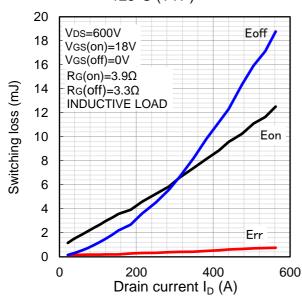


Fig.14 Switching loss vs drain current at 150°C (TYP)

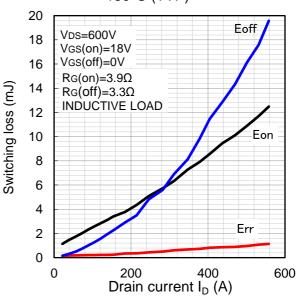


Fig.15 Recovery characteristic vs drain current at 25°C (TYP)

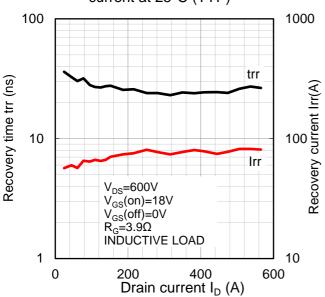


Fig.16 Recovery characteristic vs drain current at 125°C (TYP)

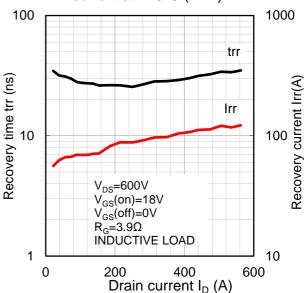


Fig.17 Recovery characteristic vs drain current at 150°C (TYP) 100 1000 trr Recovery time trr (ns) Recovery current Irr(A) Irr 10 100 V_{DS}=600V V_{GS} (on)=18V V_{GS} (off)=0V R_{G} =3.9 Ω INDUCTIVE LOAD 1 10 600 0 200 400 Drain current I_D (A)

at 25°C (TYP) 1000 V_{DS}=600V I_D=300A V_{GS}(on)=18V td(off) V_{GS}(off)=0V Switching time (ns) INDUCTIVE LOAD 100 td(on) tf 10 1 10 Gate resistance $R_G(\Omega)$

Fig.18 Switching time vs gate resistance

Fig.19 Switching time vs gate resistance at 125°C (TYP)

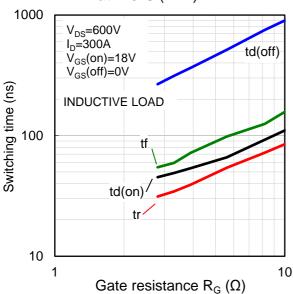


Fig.20 Switching time vs gate resistance at 150°C (TYP)

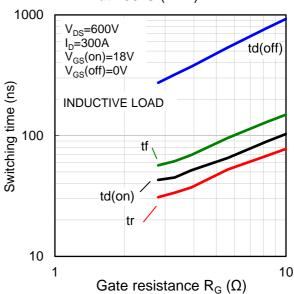


Fig.21 Switching loss vs gate resistance at 25°C (TYP)

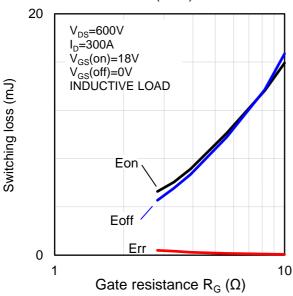


Fig.22 Switching loss vs gate resistance at 125°C (TYP)

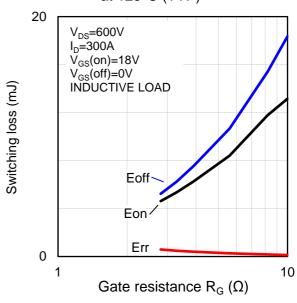


Fig.23 Switching loss vs gate resistance at 150°C (TYP)

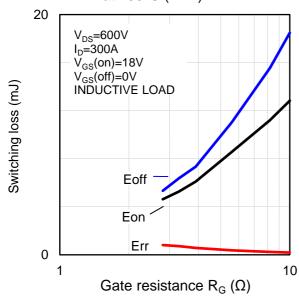
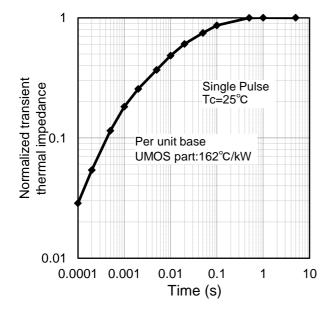


Fig.24 Capacitance vs Drain source voltage (TYP) 1.E-07 Ciss 1.E-08 Coss Tj=25°C V_{GS}=0V 200kHz 1.E-10 Crss 1.E-11 0.01 0.1 10 100 1000 Drain source voltage V_{DS} (V)

25 (S) 20 (D) 20

Fig.25 Gate charge characteristic (TYP)

Fig.26 Transient thermal impedance (TYP)



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